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|  | <p><b>SIE820DF-T1-GE3</b></p> <p><b>Hersteller-Teilenummer:</b> SIE820DF-T1-GE3</p> <p><b>Hersteller / Marke:</b> Electro-Films (EFI) / Vishay</p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 20V 50A POLARPAK</p> <p><b>Datenblätter:</b>  <a href="#">SIE820DF-T1-GE3.pdf</a></p> <p><b>RoHS Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 730 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p> |
|  |   |
| <p>Image may be representation.<br/>See specs for product details.</p>            |   |

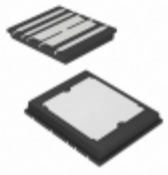
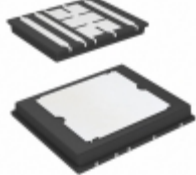
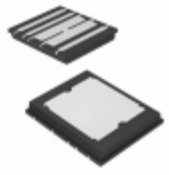
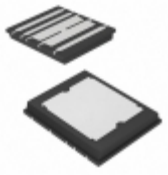
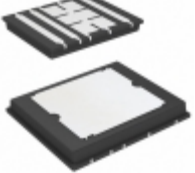
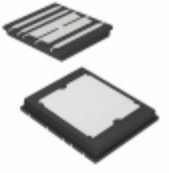
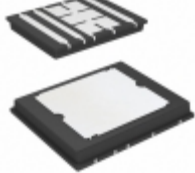
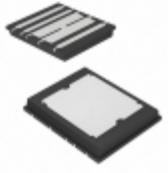
### Spezifikationen

|  |   |
|--|---|
| Teilenummer                                      | SIE820DF-T1-GE3   |
| Hersteller                                       | Electro-Films (EFI) / Vishay  |
| Beschreibung                                     | MOSFET N-CH 20V 50A POLARPAK  |
| Kategorie  | <a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> , |
| Teilstatus                                       | 730 pcs Stock   |
| VGS (th) (Max) @ Id                              | 2V @ 250µA  |
| Vgs (Max)  | ±12V  |
| Technologie                                      | MOSFET (Metal Oxide)  |
| Supplier Device-Gehäuse                          | 10-PolarPAK® (S)  |
| Serie  | TrenchFET®  |
| Rds On (Max) @ Id, Vgs                           | 3.5 mOhm @ 18A, 4.5V  |
| Verlustleistung (max)                            | 5.2W (Ta), 104W (Tc)  |
| Verpackung                                       | Original-Reel®  |
| Verpackung / Gehäuse                             | 10-PolarPAK® (S)  |
| Andere Namen                                     | SIE820DF-T1-GE3DKR  |
| Betriebstemperatur                               | -55°C ~ 150°C (TJ)  |
| Befestigungsart                                  | Surface Mount   |
| Feuchtigkeitsempfindlichkeitsniveau (MSL)        | 1 (Unlimited)   |
| Bleifreier Status / RoHS-Status                  | Lead free / RoHS Compliant  |
| Eingabekapazität (Ciss) (Max) @ Vds              | 4300pF @ 10V  |
| Gate Charge (Qg) (Max) @ Vgs                     | 143nC @ 10V   |
| Typ FET  | N-Channel   |
| FET-Merkmal                                      | -   |
| Antriebsspannung (Max Rds On, Min Rds On)        | 2.5V, 4.5V  |
| Drain-Source-Spannung (Vdss)                     | 20V   |
| detaillierte Beschreibung                        | N-Channel 20V 50A (Tc) 5.2W (Ta), 104W (Tc) Surface                               |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 50A (Tc)  |

SIE820DF-T1-GE3 Electronic Components ist ein 100% neues Original von YIC Distributor, SIE820DF-T1-GE3-Datenblätter durchsuchen, PDF, Inventar bei Y-IC.com Online, SIE820DF-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen bestellen. Versand per DHL / FedEx / TNT / UPS Express. Unterstützung der Zahlung mit telegrafischer Überweisung (T / T) oder PayPal.

RFQ SIE820DF-T1-GE3 E-Mail: [Info@Y-IC.com](mailto:Info@Y-IC.com)

### Sie können auch interessiert

|  |   |   |  |
|--|---|---|--|
| <p>sein:</p>  <p><b>SIE822DF-T1-GE3</b><br/>Vishay Siliconix<br/>MOSFET N-CH 20V 50A<br/>POLARPAK</p> |  <p><b>SIE818DF-T1-GE3</b><br/>Vishay Siliconix<br/>MOSFET N-CH 75V 60A<br/>POLARPAK</p> |  <p><b>SIE822DF-T1-GE3</b><br/>Electro-Films (EFI) / Vishay<br/>MOSFET N-CH 20V 50A<br/>POLARPAK</p>    |  <p><b>SIE820DF-T1-E3</b><br/>Electro-Films (EFI) / Vishay<br/>MOSFET N-CH 20V 50A 10-<br/>POLARPAK</p> |
|  <p><b>SIE818DF-T1-GE3</b><br/>Electro-Films (EFI) / Vishay<br/>MOSFET N-CH 75V 60A<br/>POLARPAK</p>  |  <p><b>SIE820DF-T1-GE3</b><br/>Vishay Siliconix<br/>MOSFET N-CH 20V 50A<br/>POLARPAK</p> |  <p><b>SIE818DF-T1-E3</b><br/>Electro-Films (EFI) / Vishay<br/>MOSFET N-CH 75V 60A 10-<br/>POLARPAK</p> |  <p><b>SIE822DF-T1-E3</b><br/>Vishay Siliconix<br/>MOSFET N-CH 20V 50A 10-<br/>POLARPAK</p>             |

### Verwandtes Hot-Keyword

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|  |   |  |                                       |  |
|--|---|--|---------------------------------------|--|
| <a href="#">SIE820DF-T1-GE3 Electro-Films (EFI) / Vishay</a> | <a href="#">SIE820DF-T1-GE3 Datenblatt</a>  | <a href="#">SIE820DF-T1-GE3-Datenblätter</a> | <a href="#">SIE820DF-T1-GE3 PDF</a>   | <a href="#">Electro-Films (EFI) / Vishay SIE820DF-T1-GE3</a> |
| <a href="#">SIE820DF-T1-GE3 Electronic</a>                   | <a href="#">SIE820DF-T1-GE3-Komponenten</a> | <a href="#">SIE820DF-T1-GE3-Verteiler</a>    | <a href="#">SIE820DF-T1-GE3-Bild</a>  | <a href="#">SIE820DF-T1-GE3-Teil</a>                         |
| <a href="#">SIE820DF-T1-GE3 Preis</a>                        | <a href="#">SIE820DF-T1-GE3 Hersteller</a>  | <a href="#">SIE820DF-T1-GE3 Bild</a>         | <a href="#">SIE820DF-T1-GE3 Aktie</a> | <a href="#">SIE820DF-T1-GE3 Inventar</a>                     |
| <a href="#">SIE820DF-T1-GE3 Neu</a>                          | <a href="#">SIE820DF-T1-GE3 Original</a>    | <a href="#">SIE820DF-T1-GE3 garantiert</a>   | <a href="#">SIE820DF-T1-GE3 RFQ</a>   | <a href="#">SIE820DF-T1-GE3 Online bestellen</a>             |

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